CURRICULUM VITAE

NAME: CURRENT POSITION: *OFFICE ADDRESS:*

OFFICE PHONE: OFFICE FAX: EMAIL:

Zacharias Hatzopoulos

Associate Professor, Physics Department, University of Crete, Greece Physics Department, University of Crete, Heraklion, 714 03, Crete, Greece +30-2810-394109 +30-2810-394106 <u>chatzop@physics.uoc.gr</u>

EDUCATION - DEGREES

- 4-year B.Sc. in Physics, Physics Department, Aristotle University of Thessaloniki, 1974
- Diploma in Electronics, University of Wales, Great Britain, 1975
- PhD in Physics, University of Wales. Title: «Dc size effects and electrical conduction in semimetals», 1979

BIOGRAPHICAL

- Military Service in the Greek Army, 1979-1981
- Lecturer-Researcher, Physics Department, University of Crete, 1981-1985
- Lecturer, Physics Department, University of Crete, 1985-1988
- Assistant Professor, Physics Department, University of Crete, 1988-1992
- Assistant Professor with tenure, Physics Department, University of Crete, 1992 -2008
- Associate Professor, Physics Department, University of Crete, 2008-up to now
- Researcher, Foundation for Research and Technology Hellas, 1984 up to now

EXPERIENCE / FIELDS OF RESEARCH

My research interests are in the field of MBE grown III-V compound semiconductors (arsenides).

I am heading the III-V Arsenides Molecular Beam Epitaxy activities. I have extensive experience, more than 30 years, in growth with MBE a variety of different devices.

I have been involved in the following research areas:

- Atomic Layer Epitaxy
- Laser Assisted MBE

– Growth of lattice matched InGaAs/InAlAs on InP

I have studied a plethora of devices like HEMTs, MESFETs, Pseudomorphic HEMTs, solid state LEDs, Solar Cells, and Sensors..

I am currently involved with the study of Polariton LEDs, Quantum Dots and Nanowires.

I have over 130 papers publications in refereed Journals and numerous conference presentations and has been involved in several Research Programs (European and Greek).

OTHER

- Visiting Research Scientist, Naval Research Laboratory, Washinghton D.C., USA
- Visiting Research Scientist, Electrotechnical Laboratory, Tsukuba, Japan
- Co-author, Chapter 18: «Rapid Thermal Processing of Contacts and Buffer Layers for Compound Semiconductor Device Technology». Title of book: «Advances in Rapid Thermal and Integrated Processing», F. Roozeboom (ed.), p. 493, Kluwer Academic (1996)

Recent Publications

Title: Hidden polarization of unpolarized light

Author(s): Kozlov GG , Ryzhov II , Tzimis A , Hatzopoulos Z , Savvidis PG , Kavokin AV , Bayer M, Zapasskii, VS.

Source: Physical Review A, Volume:98, Issue:4, Article Number:043810 DOI:10.1103/PhysRevA.98.043810 Published: OCT 5 2018

Title: Stochastic spin flips in polariton condensates: nonlinear tuning from GHz to sub-Hz. Author(s): Redondo YDVI, Ohadi H, Rubo YG, Beer O, Ramsay AJ, Tsintzos SI, Hatzopoulos Z, Savvidis PG, Baumberg,JJ Source: NEW JOURNAL OF PHYSICS Volume: 20 Article Number: 089601 DOI: 10.1088/1367-2630/aad934 Published: AUG 21 2018

Title: Generation of Quantized Polaritons below the Condensation ThresholdAuthor(s): Cristofolini P, Hatzopoulos Z, Savvidis PG, Baumberg JJ.Source: PHYSICALREVIEWLETTERSVolume: 121Number: 067401DOI: 10.1103/PhysRevLett.121.067401Published: AUG 7 2018

Title: Electrical Tuning of Nonlinearities in Exciton-Polariton CondensatesAuthor(s): Tsintzos SI , Tzimis A, Stavrinidis G, Trifonov A, Hatzopoulos Z, Baumberg JJ, OhadiH, Savvidis PG.Source: PHYSICALREVIEWNumber: 037401DOI: 10.1103/PhysRevLett.121.037401Published: JUL 16 2018

Title: An exciton-polariton bolometer for terahertz radiation detection Author(s): Paschos GG, Liew TCH, Hatzopoulos Z, Kavokin AV, Savvidis PG, Deligeorgis G. Source: SCIENTIFIC REPORTS Volume: 8 Article Number: 10092 DOI: 10.1038/s41598-018-28197-0 Published: JUL 4 2018

Title: All-optical quantum fluid spin beam splitter Author(s): Askitopoulos A, Nalitov AV, Sedov ES, Pickup L, Cherotchenko ED, Hatzopoulos Z, Savvidis PG, Kavokin AV, Lagoudakis PG. Source: PHYSICAL REVIEW B Volume: 97 Issue: 23 Article Number: 235303 DOI: 10.1103/PhysRevB.97.235303 Published: JUN 6 2018